

# Enrique G Michel

## List of Publications by Year in descending order

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130  
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2,596  
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186265

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133  
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times ranked

1783  
citing authors

#	ARTICLE	IF	CITATIONS
1	Pyrenetetraone-based covalent organic framework as an effective electrocatalyst for oxygen reduction reaction. <i>Nano Research</i> , 2022, 15, 3907-3912.	10.4	14
2	Preparation of high-quality few-layers bismuthene hexagons. <i>Applied Materials Today</i> , 2022, 26, 101360.	4.3	9
3	Acidic triggering of reversible electrochemical activity in a pyrenetetraone-based 2D polymer. <i>Polymer</i> , 2021, 212, 123273.	3.8	1
4	Exfoliation of Alpha-Germanium: A Covalent Diamond-Like Structure. <i>Advanced Materials</i> , 2021, 33, e2006826.	21.0	27
5	Continuous-Flow Synthesis of High-Quality Few-Layer Antimonene Hexagons. <i>Advanced Functional Materials</i> , 2021, 31, 2101616.	14.9	8
6	Understanding the intrinsic compression in polycrystalline films through a mean-field atomistic model. <i>Journal Physics D: Applied Physics</i> , 2021, 54, 065302.	2.8	0
7	In-plane Néel wall chirality and orientation of interfacial Dzyaloshinskii-Moriya vector in magnetic films. <i>Physical Review B</i> , 2020, 102, .	3.2	6
8	Large Dzyaloshinskii-Moriya interaction induced by chemisorbed oxygen on a ferromagnet surface. <i>Science Advances</i> , 2020, 6, eaba4924.	10.3	60
9	Unveiling the oxidation behavior of liquid-phase exfoliated antimony nanosheets. <i>2D Materials</i> , 2020, 7, 025039.	4.4	33
10	Synergistic Effect of Covalent Bonding and Physical Encapsulation of Sulfur in the Pores of a Microporous COF to Improve Cycling Performance in Li-S Batteries. <i>Chemistry - A European Journal</i> , 2019, 25, 12394-12404.	3.3	37
11	Tunable Graphene Electronics with Local Ultrahigh Pressure. <i>Advanced Functional Materials</i> , 2019, 29, 1806715.	14.9	15
12	Liquid phase exfoliation of antimonene: systematic optimization, characterization and electrocatalytic properties. <i>Journal of Materials Chemistry A</i> , 2019, 7, 22475-22486.	10.3	54
13	Crystalline Structure and Vacancy Ordering across a Surface Phase Transition in Sn/Cu(001). <i>Journal of Physical Chemistry B</i> , 2018, 122, 745-756.	2.6	1
14	Disclosing the origin of the postcoalescence compressive stress in polycrystalline films by nanoscale stress mapping. <i>Physical Review B</i> , 2018, 98, .	3.2	5
15	Noncovalent Functionalization and Charge Transfer in Antimonene. <i>Angewandte Chemie - International Edition</i> , 2017, 56, 14389-14394.	13.8	83
16	Noncovalent Functionalization and Charge Transfer in Antimonene. <i>Angewandte Chemie</i> , 2017, 129, 14581-14586.	2.0	26
17	Effect of a skin-deep surface zone on the formation of a two-dimensional electron gas at a semiconductor surface. <i>Physical Review B</i> , 2016, 94, .	3.2	7
18	Evolution of the electronic structure during the epitaxial growth of Au on Pt(100). <i>Surface Science</i> , 2016, 646, 126-131.	1.9	0

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19	Lateral confinement effects of $M\tilde{A}$ -point Tamm state in vicinal Cu(100) surfaces. <i>Surface Science</i> , 2014, 630, 144-152.	1.9	1
20	Surface electronic structure of InSb(001)-c(8 $\tilde{A}$ —2). <i>Surface Science</i> , 2013, 608, 22-30.	1.9	4
21	Competing charge ordering and Mott phases in a correlated Sn/Ge(111) two-dimensional triangular lattice. <i>Physical Review B</i> , 2013, 88, .	3.2	23
22	The dimensionality reduction at surfaces as a playground for many-body and correlation effects. <i>Journal of Physics Condensed Matter</i> , 2013, 25, 090301.	1.8	1
23	Electronic structure of reconstructed Au(100): Two-dimensional and one-dimensional surface states. <i>Physical Review B</i> , 2012, 86, .	3.2	23
24	Electron correlation and many-body effects at interfaces on semiconducting substrates. <i>Physica Status Solidi (A) Applications and Materials Science</i> , 2012, 209, 614-626.	1.8	16
25	Effect of photoelectron mean free path on the photoemission cross-section of Cu(111) and Ag(111) Shockley states. <i>Physical Review B</i> , 2011, 84, .	3.2	14
26	Determination of the photoelectron reference plane in nanostructured surfaces. <i>New Journal of Physics</i> , 2011, 13, 103013.	2.9	5
27	Perspectives on surface science. <i>Journal of Physics Condensed Matter</i> , 2010, 22, 080302.	1.8	1
28	Order-disorder phase transition of vacancies in surfaces: The case of Sn/Cu(001)-0.5 ML. <i>Physical Review B</i> , 2010, 82, .	3.2	5
29	Enhancement of $T_c$ , orthorhombicity and AC magnetic shielding in argon preheated HTC superconductor $(Y_{1-x}Sm_x)(SrBa)Cu_3O_{6+z}$ . <i>IOP Conference Series: Materials Science and Engineering</i> , 2010, 13, 012008.	0.6	1
30	Structure of the indium-rich InSb(001) surface. <i>Physical Review B</i> , 2010, 82, .	3.2	14
31	Structural and electronic properties of $M\tilde{A}$		

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37	<p>al Origin of the Sn <math display="inline">\frac{4}{d}</math> Core Level Line Shape in <math display="inline">\text{Sn} \langle \text{Ge} \rangle \langle 111 \rangle</math> stretchy="false"&gt;&lt;/mml:mo&gt;&lt;mml:mn&gt;111&lt;/mml:mn&gt;&lt;mml:mo stretchy="false"&gt;&lt;/mml:mo&gt;&lt;mml:mtext mathvariant="normal"&gt;â&lt;/mml:mtext&gt;&lt;/mml:mo&gt;</p>		

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55	Accurate band mapping via photoemission from thin films. <i>Physical Review B</i> , 2004, 69, .	3.2	6
56	Surface electronic structure of a vicinal Cu crystal. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 2003, 21, 1194-1197.	2.1	11
57	Phonon Softening, Chaotic Motion, and Order-Disorder Transition in Sn/Ge(111). <i>Physical Review Letters</i> , 2003, 91, 016103.	7.8	43
58	Electronic structure of Sn/Si(111)-(3Å-3)R30° as a function of Sn coverage. <i>Physical Review B</i> , 2003, 68, .	3.2	17
59	Electronic structure of $\text{Si}_x\text{Sn}(1-x)/\text{Si}(111)-(3\text{\AA}-3)R30^\circ$ phases. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 2003, 21, 1298-1301.	2.1	1
60	NEXAFS experiment and multiple scattering calculations on KO <sub>2</sub> : Effects on the $\tilde{\Gamma}$ resonance in the solid phase. <i>Physical Review B</i> , 2002, 66, .	3.2	12
61	Reversible structural phase transitions in semiconductor and metal/semiconductor surfaces. <i>Journal of Physics Condensed Matter</i> , 2002, 14, 6005-6035.	1.8	22
62	Transition from terrace to step modulation in the surface state wave function at vicinal Cu(1 1 1). <i>Surface Science</i> , 2001, 482-485, 764-769.	1.9	16
63	Probing unoccupied bulk bands via the cross section of quantum well states in thin films. <i>Surface Science</i> , 2001, 482-485, 464-469.	1.9	6
64	XSW study of oxygen/alkali metal/Si(111) interfaces. <i>Surface Science</i> , 2001, 482-485, 1283-1286.	1.9	2
65	Electronic structure and reactivity of the Co/MoS <sub>2</sub> (0 0 0 1) interface. <i>Surface Science</i> , 2001, 482-485, 664-668.	1.9	3
66	NEXAFS multiple scattering calculations of KO <sub>2</sub> . <i>Journal of Synchrotron Radiation</i> , 2001, 8, 719-721.	2.4	1
67	Electron Wave Function at a Vicinal Surface: Switch from Terrace to Step Modulation. <i>Physical Review Letters</i> , 2000, 84, 6110-6113.	7.8	72
68	Periodicity and thickness effects in the cross section of quantum well states. <i>Physical Review B</i> , 2000, 62, 12672-12675.	3.2	21
69	Symmetry breaking and atomic displacements in the 3Å-3 surface phase of Pb/Ge(111). <i>Surface Science</i> , 2000, 454-456, 191-195.	1.9	1
70	Dynamical Fluctuations as the Origin of a Surface Phase Transition in Sn/Ge(111). <i>Physical Review Letters</i> , 1999, 82, 442-445.	7.8	173
71	Nature of the Low-Temperature 3Å-3 Surface Phase of Pb/Ge(111). <i>Physical Review Letters</i> , 1999, 82, 2524-2527.	7.8	47
72	Fermi surface of a triangular lattice overlayer: Pb/Ge(111) $\hat{1}\pm$ -phase. <i>Journal of Electron Spectroscopy and Related Phenomena</i> , 1999, 101-103, 361-365.	1.7	5

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73	Spin-polarized quantum well states. Journal of Electron Spectroscopy and Related Phenomena, 1999, 101-103, 367-370.	1.7	6
74	Short wavelength, spin-polarized quantum-well states in high quality Cu films on FCC-Co(100). Journal of Magnetism and Magnetic Materials, 1999, 203, 126-128.	2.3	9
75	Resonant quantum well states in thin copper films on fcc-Co(100). Surface Science, 1999, 433-435, 425-429.	1.9	3
76	Electronic band structure of Ge(111)(3Å-3)-Pb. Surface Science, 1999, 433-435, 337-341.	1.9	6
77	Electronic instabilities of the two-dimensional Sn/Ge(111) $\hat{I}_{\pm}$ -phase. Surface Science, 1999, 433-435, 327-331.	1.9	16
78	Phase transition of submonolayer Pb/Ge(111): $\hat{I}_{\pm}$ $\hat{\nu}$ 3Å-3R30Å° $\hat{\alpha}^{\dagger}$ 3 Å- 3at $\hat{\nu}$ ¼ 250 K. Applied Surface Science, 1998, 123-124, 626-630.	6.1	10
79	Band structure and gap opening in Pb/Ge(111). Surface Science, 1998, 402-404, 742-745.	1.9	7
80	Quantum well states and interface quality in Cu/Co(100)/Cu(100) system. Surface Science, 1998, 402-404, 377-381.	1.9	3
81	Electronic band structure of epitaxial 3Å-3R30Å° $\hat{I}_{\mu}$ -FeSi(111)/Si(111). Physical Review B, 1998, 57, 1414-1417.	3.2	10
82	Quantum well states in high-quality Cu films deposited on Co (100): A high resolution photoemission study. Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films, 1998, 16, 1368-1373.	2.1	2
83	Fermi surface and electronic structure of Pb/Ge(111). Physical Review B, 1998, 57, 14758-14765.	3.2	36
84	Electronic band structure of (100). Journal of Physics Condensed Matter, 1997, 9, 1871-1876.	1.8	1
85	INTERPLAY OF ELECTRONIC AND GEOMETRIC STRUCTURE IN A MODEL SYSTEM: EPITAXIAL IRON SILICIDES. Surface Review and Letters, 1997, 04, 319-326.	1.1	1
86	Surface electronic structure of metastable FeSi(CsCl)(111) epitaxially grown on Si(111). Physical Review B, 1997, 55, R16065-R16068.	3.2	12
87	Atomic structure of the reactive Fe/Si(111)7Å-7 interface. Physical Review B, 1997, 55, R7315-R7318.	3.2	40
88	Iron silicides grown on Si(100): metastable and stable phases. Surface Science, 1997, 371, 297-306.	1.9	31
89	Metallization onset in. Surface Science, 1997, 377-379, 220-224.	1.9	7
90	Oxygen interaction with Si(100) and. Surface Science, 1997, 377-379, 650-654.	1.9	12

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91	interface formation studied by photoelectron diffraction. Surface Science, 1997, 377-379, 856-860.	1.9	13
92	Metastable iron silicide phase stabilized by surface segregation on Fe <sub>3</sub> Si(100). Surface Science, 1997, 381, 133-141.	1.9	21
93	Epitaxial iron silicides: geometry, electronic structure and applications. Applied Surface Science, 1997, 117-118, 294-302.	6.1	33
94	Origin of the surface metallization in single-domain K/Si(100)2Å–1. Physical Review B, 1996, 54, R14277-R14280.	3.2	10
95	Quantum Well States and Short Period Oscillations of the Density of States at the Fermi Level in Cu Films Grown on fcc Co(100). Physical Review Letters, 1996, 77, 3455-3458.	7.8	62
96	Surface dangling bond state in Si(111) and epitaxial $\hat{\Gamma}^2$ -FeSi <sub>2</sub> films: a comparative photoelectron spectroscopy study. Surface Science, 1995, 330, 34-40.	1.9	7
97	Structural phase transition during heteroepitaxial growth of iron silicides on Si(111). Applied Surface Science, 1993, 70-71, 578-582.	6.1	8
98	RbBr/Si(111) interface studied by the X-ray standing wave method. Surface Science, 1993, 287-288, 288-293.	1.9	2
99	Determination of the Fe/Si(111) phase diagram by means of photoelectron spectroscopies. Surface Science, 1993, 287-288, 490-494.	1.9	30
100	Initial stages of the growth of Fe on Si(111)7Å–7. Physical Review B, 1993, 47, 16048-16051.	3.2	84
101	Geometric and electronic structure of epitaxial iron silicides. Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films, 1993, 11, 929-933.	2.1	28
102	X-ray standing wave study of alkali-metal/silicon interfaces. Journal of Physics Condensed Matter, 1993, 5, A85-A88.	1.8	6
103	X-ray standing-wave study of alkali-metal/Si(111)7Å–7 interfaces. Physical Review B, 1993, 48, 12023-12031.	3.2	4
104	Adsorption of Rb on Si(211)2Å–1 studied by the x-ray standing wave technique. Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films, 1993, 11, 1812-1816.	2.1	3
105	Structural and electronic properties of K/Si(100)2Å–1. Physical Review B, 1992, 45, 11811-11822.	3.2	63
106	Electronic structure of iron silicides grown on Si(100) determined by photoelectron spectroscopies. Physical Review B, 1992, 45, 14042-14051.	3.2	76
107	Adsorption sites of Br on Si(211) investigated with X-ray standing wave fields. Surface Science, 1992, 269-270, 89-93.	1.9	7
108	Study of the electronic structure of iron silicides grown on Si(100)2 Å– 1 by reactive deposition epitaxy. Surface Science, 1992, 269-270, 1011-1015.	1.9	10

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109	The adsorption geometry of Cs on Si(110). <i>Applied Surface Science</i> , 1992, 56-58, 457-462.	6.1	7
110	Adsorption of I on Si(111) and Si(110) surfaces. <i>Surface Science</i> , 1991, 241, 111-123.	1.9	23
111	The growth and characterization of iron silicides on Si(100). <i>Surface Science</i> , 1991, 251-252, 59-63.	1.9	28
112	Adsorption sites of Rb and Br on the Si(100)2 Å <sup>-1</sup> surface. <i>Surface Science</i> , 1991, 251-252, 483-487.	1.9	26
113	Photoelectron yield excited by an X-ray standing wave with synchrotron radiation: energy-dispersive measurements with a magnetic analyzer. <i>Nuclear Instruments and Methods in Physics Research, Section A: Accelerators, Spectrometers, Detectors and Associated Equipment</i> , 1991, 308, 278-281.	1.6	0
114	X-ray standing-wave study of Cs/Si(111)7 Å <sup>-1</sup> . <i>Physical Review B</i> , 1991, 44, 4036-4039.	3.2	22
115	Surface characterization of epitaxial, semiconducting, FeSi <sub>2</sub> grown on Si(100). <i>Applied Physics Letters</i> , 1991, 59, 99-101.	3.3	45
116	Potassium interaction with Si(100)2 Å <sup>-1</sup> surface. <i>Vacuum</i> , 1990, 40, 230.	3.5	0
117	Interaction of potassium with Si(100)2 Å <sup>-1</sup> . <i>Vacuum</i> , 1990, 41, 564-566.	3.5	27
118	Local versus non-local character of the alkali-promoted oxidation of silicon. <i>Vacuum</i> , 1990, 41, 787-789.	3.5	6
119	Properties of potassium adsorbed on Si(100)2 Å <sup>-1</sup> . <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 1989, 7, 1885-1888.	2.1	36
120	A structural study of the K adsorption site on a Si(001)2 Å <sup>-1</sup> surface: Dimer, caves or both. <i>Surface Science</i> , 1989, 211-212, 31-38.	1.9	33
121	Epitaxy of Pt on Au(001): Growth mode, interface state and Pt core-level shifts. <i>Surface Science</i> , 1988, 198, L365-L374.	1.9	10
122	Photoemission study of a high-T <sub>c</sub> superconducting Bi-Sr-Ca-Cu oxide. <i>Physical Review B</i> , 1988, 38, 5146-5149.	3.2	35
123	Early stages of the alkali-metal-promoted oxidation of silicon. <i>Physical Review B</i> , 1988, 38, 13399-13406.	3.2	101
124	K/Si(100) 2 Å <sup>-1</sup> : A Case Study for the Transfer of Charge between Alkali Metals and Semiconductor Surfaces. <i>Europhysics Letters</i> , 1988, 5, 727-732.	2.0	44
125	Empty Interface State in Pt/Au(001) Revealed by Inverse Photoemission. <i>Europhysics Letters</i> , 1987, 4, 603-608.	2.0	1
126	Ultrathin gate oxides formed by catalytic oxidation of silicon. <i>Applied Physics Letters</i> , 1987, 50, 1660-1662.	3.3	53



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127	Mechanism of alkali-promoted oxidation of silicon. Applied Physics Letters, 1987, 51, 1714-1716.	3.3	60
128	Alkali-induced oxidation of silicon. Surface Science, 1987, 189-190, 245-251.	1.9	54
129	Inverse photoemission of metal epitaxial growth: Evidence for an empty interface state. Surface Science, 1987, 189-190, 393-398.	1.9	1
130	A new high temperature superconductor: Ba <sub>2</sub> SmCu <sub>3</sub> O <sub>9-x</sub> . Solid State Communications, 1987, 63, 507-510.	1.9	32